## NSN 5961-01-044-6385

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View Online at https://aerobasegroup.com/nsn/5961-01-044-638
Inclosure Material:
Metal
Overall Length:
0.260 inches
Overall Height:
0.260 inches
Overall Diameter:
0.370 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 collector to emitter voltage, dc
Current Rating Per Characteristic:
5.00 amperes source cutoff current
Power Rating Per Characteristic:
6.0 watts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:

98230-0n196166 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Terminal Type And Quantity:** 

3 uninsulated wire lead

## Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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